

MT29RZ4B2DZZHGSK-18 W.80E

MT29RZ4B2DZZHGSK-18 W.80E Information

Heisener.com	 MT29RZ4B2DZZHGSK-18 W.80E Micron Technology Inc. Integrated Circuits (ICs) Memory IC FLASH 6G DDR2 - For the pricing/inventory/lead time, please contact	
For Reference Only	us Website: https://www.heisener.com E-mail: salesdept@heisener.com	Request a Quote

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



MT29RZ4B2DZZHGSK-18 W.80E Specifications

Manufacturer Part Number	MT29RZ4B2DZZHGSK-18 W.80E	
Manufacturer	Micron Technology Inc.	
Category	Integrated Circuits (ICs)	
	Memory	
Package	-	
Series	-	
Memory Type	Non-Volatile	
Memory Format	FLASH, RAM	
Technology	FLASH - NAND, DRAM - LPDDR2	
Memory Size	4Gb (512M x 8)(NAND), 2G (64M x 32)(LPDDR2)	
Memory Interface	Parallel	
Clock Frequency	533MHz	
Write Cycle Time - Word, Page	-	
Access Time	-	
Voltage - Supply	1.8V	
Operating Temperature	-25°C ~ 85°C (TA)	
Mounting Type	-	
Package / Case	-	
Supplier Device Package	-	
	Report err	ors?

MT29RZ4B2DZZHGSK-18 W.80E Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE BUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

MT29RZ4B2DZZHGSK-18 W.80E Payment Methods



If you have any question about MT29RZ4B2DZZHGSK-18 W.80E, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com